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19-5328; Rev 0; 7/10

EVALUATION KIT AVAILABLE

0 to 16V, Hot-Swap Controller with 10-Bit Current, Voltage Monitor, and 4 LED Drivers

General Description

The MAX5978 hot-swap controller provides complete protection for systems with a supply voltage from 0 to 16V. The device includes four programmable LED outputs.

The IC provides two programmable levels of overcurrent circuit-breaker protection: a fast-trip threshold for a fast turn-off, and a lower slow-trip threshold for a delayed turn-off. The maximum overcurrent circuit-breaker threshold range is set with a trilevel logic input (IRNG), or by programming through the I²C interface.

The IC is an advanced hot-swap controller that monitors voltage and current with an internal 10-bit ADC, which is continuously multiplexed to convert the output voltage and current at 10ksps. Each 10-bit sample is stored in an internal circular buffer so that 50 past samples of each signal can be read back through the I²C interface at any time or after a fault condition.

The device includes five user-programmable digital comparators to implement overcurrent warning and two levels of overvoltage/undervoltage detection. When measured values violate the programmable limits, an external $\overline{\text{ALERT}}$ output is asserted. In addition to the $\overline{\text{ALERT}}$ signal, the IC can be programmed to deassert the power-good signal and/or turn off the external MOSFET.

The IC features four I/Os that can be independently configured as general-purpose input/outputs (GPIOs) or as open-drain LED drivers with programmable blinking. These four I/Os can be configured for any mix of LED driver or GPIO function.

The device is available in a 32-pin thin QFN-EP package and operates over the -40°C to +85°C extended temperature range.

Ordering Information

PART	TEMP RANGE	PIN-PACKAGE
MAX5978ETJ+	-40°C to +85°C	32 TQFN-EP*

+Denotes a lead(Pb)-free/RoHS-compliant package.
**EP = Exposed pad.*

Features

- **Hot-Swap Controller Operates from 0 to 16V**
- **10-Bit ADC Monitors Load Voltage and Current**
- **Circular Buffers Store 5ms of Current and Voltage Measurements**
- **Internal Charge Pump Generates n-Channel MOSFET Gate Drive**
- **Internal 500mA Gate Pulldown Current for Fast Shutdown**
- **VariableSpeed/Bilevel™ Circuit-Breaker Protection**
- **Precision-Voltage Enable Input**
- **Alert Output Indicates Fault and Warning Conditions**
- **Open-Drain Power-Good Output with Programmable Polarity**
- **Open-Drain Fault Output**
- **Four Open-Drain General-Purpose Outputs Sink 25mA to Directly Drive LEDs**
- **Programmable LED Flashing Function**
- **Latched-Off Fault Management**
- **400kHz I²C Interface**
- **Small, 5mm x 5mm, 32-Pin TQFN-EP Package**

Applications

Blade Servers

DC Power Metering

Disk Drives/DASD/Storage Systems

Soft-Switch for ASICs, FPGAs, and Microcontrollers

Network Switches/Routers

VariableSpeed/Bilevel is a trademark of Maxim Integrated Products, Inc.

0 to 16V, Hot-Swap Controller with 10-Bit Current, Voltage Monitor, and 4 LED Drivers

ABSOLUTE MAXIMUM RATINGS

IN, SENSE, MON, GATE to AGND ..... -0.3V to +30V
LED_ to AGND .....-0.3V to +16V
PG, ON, ALERT, FAULT, SDA, SCL to AGND .....-0.3V to +6V
REG, DREG, IRNG, MODE, PROT, A_ to AGND ...-0.3V to +4V
REG to DREG .....-0.3V to +0.3V
HWEN, POL to AGND .....-0.3V to (V_{REG} + 0.3V)
GATE to MON .....-0.3V to +6V
GND, DGND to AGND .....-0.3V to +0.3V
SDA, ALERT Current ..... -20mA to +50mA
LED_ Current ..... -20mA to +100mA
GATE, MON, GND Current 750mA
All Other Pins Input/Output Current 20mA
Continuous Power Dissipation (T_A = +70°C)*
32-Pin TQFN (derate 34.5mW/°C above +70°C)..... 2759mW*
Junction-to-Ambient Thermal Resistance (θ_{JA}) (Note 1).....+29°C/W
Operating Temperature Range ..... -40°C to +85°C
Junction Temperature ..... +150°C
Storage Temperature Range ..... -65°C to +150°C
Lead Temperature (soldering, 10s) .....+300°C
Soldering Temperature (reflow) .....+260°C

**As per JEDEC51 Standard (Multilayer Board).*

Note 1: Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to **www.maxim-ic.com/thermal-tutorial**.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

(V_{IN} = 2.7V to 16V, T_A = -40°C to +85°C, unless otherwise noted. Typical values are at V_{IN} = 3.3V and T_A = +25°C.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Supply Input Voltage Range	V_{IN}			2.7		16	V
Hot-Swap Voltage Range				0		16	V
Supply Current	I_{IN}				2.5	4	mA
Internal LDO Output Voltage	REG	I_{REG} = 0 to 5mA, V_{IN} = 2.7V to 16V		2.49	2.53	2.6	V
Undervoltage Lockout	UVLO	V_{IN} rising				2.6	V
Undervoltage-Lockout Hysteresis	$UVLO_{HYS}$				100		mV
CURRENT-MONITORING FUNCTION							
MON, SENSE Input Voltage Range				0		16	V
SENSE Input Current		V_{SENSE}, V_{MON} = 16V			32	75	µA
MON Input Current		V_{SENSE}, V_{MON} = 16V			180	280	µA
Current Measurement LSB Voltage		25mV range			24.34		µV
		50mV range			48.39		
		100mV range			96.77		
Current Measurement Error (25mV Range)		V_{MON} = 0V	V_{SENSE} - V_{MON} = 5mV	-6.57		+6.22	%FS
			V_{SENSE} - V_{MON} = 20mV	-6.71		+6.82	
		V_{MON} = 2.5V to 16V	V_{SENSE} - V_{MON} = 5mV	-9.71		+8.92	
			V_{SENSE} - V_{MON} = 20mV	-10.24		+9.36	
Current Measurement Error (50mV Range)		V_{MON} = 0V	V_{SENSE} - V_{MON} = 10mV	-4.24		+3.78	%FS
			V_{SENSE} - V_{MON} = 40mV	-4.53		+5.36	
		V_{MON} = 2.5V to 16V	V_{SENSE} - V_{MON} = 10mV	-4.50		+4.00	
			V_{SENSE} - V_{MON} = 40mV	-4.20		+4.50	

ELECTRICAL CHARACTERISTICS (continued)

(V_{IN} = 2.7V to 16V, T_A = -40°C to +85°C, unless otherwise noted. Typical values are at V_{IN} = 3.3V and T_A = +25°C.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Current Measurement Error (100mV Range)		V_{MON} = 0V	V_{SENSE} - V_{MON} = 20mV	-2.70		+2.43	%FS
			V_{SENSE} - V_{MON} = 80mV	-3.63		+4.56	
		V_{MON} = 2.5V to 16V	V_{SENSE} - V_{MON} = 20mV	-3.14		+3.19	
			V_{SENSE} - V_{MON} = 80mV	-3.80		+3.93	
Fast Current-Limit Threshold Error (25mV Range)		V_{MON} = 0V	Circuit breaker, DAC = 102	-2.106		+0.888	mV
			Circuit breaker, DAC = 255	-2.986		+0.641	
		V_{MON} = 2.5V to 16V	Circuit breaker, DAC = 102	-3.000		+1.000	
			Circuit breaker, DAC = 255	-3.500		+1.500	
Fast Current-Limit Threshold Error (50mV Range)		V_{MON} = 0V	Circuit breaker, DAC = 102	-3.1188		+0.926	mV
			Circuit breaker, DAC = 255	-4.873		+0.3421	
		V_{MON} = 2.5V to 16V	Circuit breaker, DAC = 102	-3.2668		+0.9228	
			Circuit breaker, DAC = 255	-4.7		+1.0212	
Fast Current-Limit Threshold Error (100mV Range)		V_{MON} = 0V	Circuit breaker, DAC = 102	-4.7987		+1.1812	mV
			Circuit breaker, DAC = 255	-8.9236		+0.202	
		V_{MON} = 2.5V to 16V	Circuit breaker, DAC = 102	-4.9991		+0.6374	
			Circuit breaker, DAC = 255	-8.262		+1	
Slow Current-Limit Threshold Error (25mV Range)		V_{MON} = 0V	Circuit breaker, DAC = 102	-1.7965		+1.5496	mV
			Circuit breaker, DAC = 255	-1.86		+1.5916	
		V_{MON} = 2.5V to 16V	Circuit breaker, DAC = 102	-2.149		+1.9868	
			Circuit breaker, DAC = 255	-2.2285		+1.9982	
Slow Current-Limit Threshold Error (50mV Range)		V_{MON} = 0V	Circuit breaker, DAC = 102	-2.3992		+1.8723	mV
			Circuit breaker, DAC = 255	-2.5146		+2.1711	
		V_{MON} = 2.5V to 16V	Circuit breaker, DAC = 102	-2.4716		+2.181	
			Circuit breaker, DAC = 255	-2.7421		+2.1152	
Slow Current-Limit Threshold Error (100mV Range)		V_{MON} = 0V	Circuit breaker, DAC = 102	-3.3412		+2.989	mV
			Circuit breaker, DAC = 255	-3.8762		+3.6789	
		V_{MON} = 2.5V to 16V	Circuit breaker, DAC = 102	-3.2084		+2.7798	
			Circuit breaker, DAC = 255	-3.8424		+2.6483	
Fast Circuit-Breaker Response Time	t_{FCB}	Overdrive = 10% of current-sense range			2		µs
Slow Current-Limit Response Time	t_{SCB}	Overdrive = 4% of current-sense range			2.4		ms
		Overdrive = 8% of current-sense range			1.2		
		Overdrive = 16% of current-sense range			0.8		
THREE-STATE INPUTS							
A1, A0, IRNG, MODE, PROT Low Current	I_{IN_LOW}	Input voltage = 0.4V		-40			µA
A1, A0, IRNG, MODE, PROT High Current	I_{IN_HIGH}	Input voltage = V_{REG} - 0.2V				40	µA
A1, A0, IRNG, MODE, PROT Open Current	I_{FLOAT}	Maximum source/sink current for open state		-4		+4	µA
A1, A0, IRNG, MODE, PROT Low Voltage		Relative to AGND				0.4	V

0 to 16V, Hot-Swap Controller with 10-Bit Current, Voltage Monitor, and 4 LED Drivers

ELECTRICAL CHARACTERISTICS (continued)

(V_{IN} = 2.7V to 16V, T_A = -40°C to +85°C, unless otherwise noted. Typical values are at V_{IN} = 3.3V and T_A = +25°C.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
A1, A0, IRNG, MODE, PROT High Voltage		Relative to V_{REG}	-0.24			V
TWO-STATE INPUTS						
HWEN, POL Input Logic Low Voltage					0.4	V
HWEN, POL Input Logic High Voltage			V_{REG} - 0.4			V
HWEN, POL Input Current			-1		+1	µA
ON Input Voltage	V_{ON}		0.582	0.592	0.602	V
ON Input Hysteresis	V_{ONHYS}			4		%
ON Input Current			-100		+100	nA
TIMING						
MON-to-PG Delay		Register configurable (see Tables 30a and 30b)		50		ms
				100		
				200		
				400		
CHARGE PUMP (GATE)						
Charge-Pump Output Voltage		Relative to V_{MON}, I_{GATE} = 0V	4.5	5.3	5.5	V
Charge-Pump Output Source Current			4	5	6	µA
GATE Discharge Current		V_{GATE} - V_{MON} = 2V		500		mA
OUTPUT ($\overline{FAULT}$, PG, $\overline{ALERT}$)						
Output-Voltage Low		I_{SINK} = 3.2mA			0.2	V
Output Leakage Current					1	µA
LED INPUT/OUTPUT						
LED_ Input Threshold Low Level	V_{IL}				0.4	V
LED_ Input Threshold High Level	V_{IH}		1.4			V
LED_ Output Low	V_{OH}	$I_{LED\_}$ = 25mA			0.7	V
LED_ Input Leakage Current (Open Drain)	I_{GPIO_IX}	$V_{LED\_}$ = 16V	-1		+1	µA
LED_ Weak Pullup Current	I_{PU_WEAK}	$V_{LED\_}$ = V_{IN} - 0.65V	2			µA
ADC PERFORMANCE						
Resolution				10		Bits
Maximum Integral Nonlinearity	INL			1		LSB
ADC Total Monitoring Cycle Time			95	100	110	µs

ELECTRICAL CHARACTERISTICS (continued)

(V_{IN} = 2.7V to 16V, T_A = -40°C to +85°C, unless otherwise noted. Typical values are at V_{IN} = 3.3V and T_A = +25°C.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
MON LSB Voltage		16V range	15.23	15.49	15.69	mV
		8V range	7.655	7.743	7.811	
		4V range	3.811	3.875	3.933	
		2V range	1.899	1.934	1.966	
MON Code 000H to 001H Transition Voltage		16V range	10	25	41	mV
		8V range	4.7	12	21	
		4V range	2	6	12	
		2V range	0.5	3	5.5	
I²C INTERFACE						
Serial-Clock Frequency	f_{SCL}				400	kHz
Bus Free Time Between STOP and START Conditions	t_{BUF}		1.3			µs
START Condition Setup Time	$t_{SU:STA}$		0.6			µs
START Condition Hold Time	$t_{HD:STA}$		0.6			µs
STOP Condition Setup Time	$t_{SU:STO}$		0.6			µs
Clock High Period	t_{HIGH}		0.6			µs
Clock Low Period	t_{LOW}		1.3			µs
Data Setup Time	$t_{SU:DAT}$		100			ns
Data Hold Time	$t_{HD:DAT}$	Transmit	100			ns
		Receive	300		900	
Output Fall Time	t_{OF}	C_{BUS} = 10pF to 400pF			250	ns
Pulse Width of Spike Suppressed	t_{SP}			50		ns
SDA, SCL Input High Voltage	V_{IH}		1.8			V
SDA, SCL Input Low Voltage	V_{IL}				0.8	V
SDA, SCL Input Hysteresis	V_{HYST}			0.22		V
SDA, SCL Input Current			-1		+1	µA
SDA, SCL Input Capacitance				15		pF
SDA Output Voltage	V_{OL}	I_{SINK} = 4mA			0.4	V

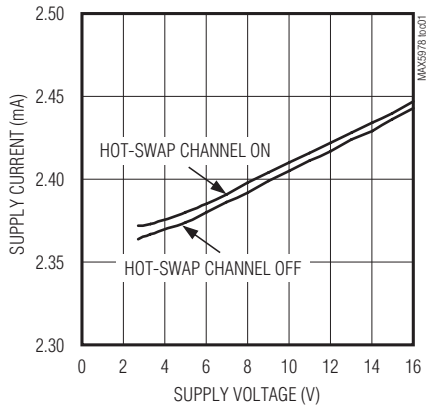
Note 2: All devices 100% production tested at T_A = +25°C. Limits over the temperature range are guaranteed by design.

0 to 16V, Hot-Swap Controller with 10-Bit Current, Voltage Monitor, and 4 LED Drivers

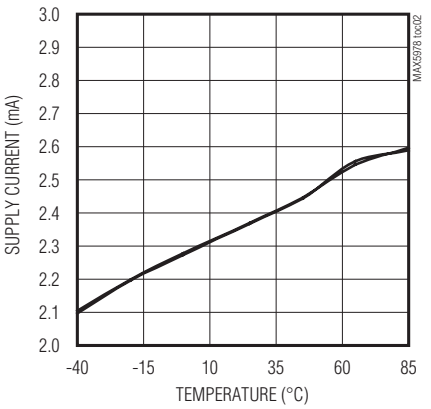
Typical Operating Characteristics

(V_{IN} = 3.3V, T_A = +25°C, unless otherwise noted.)

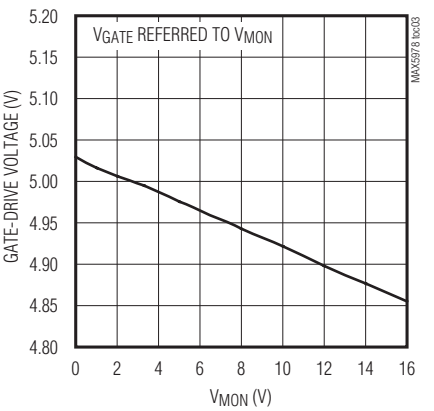
SUPPLY CURRENT vs. SUPPLY VOLTAGE



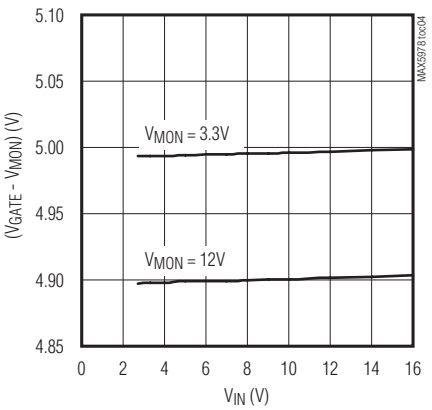
SUPPLY CURRENT vs. TEMPERATURE



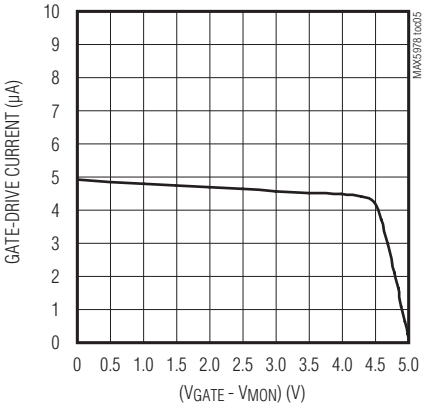
GATE-DRIVE VOLTAGE vs. V_{MON}



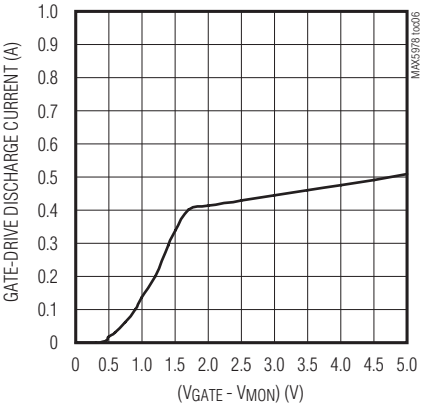
GATE-DRIVE VOLTAGE vs. V_{IN}



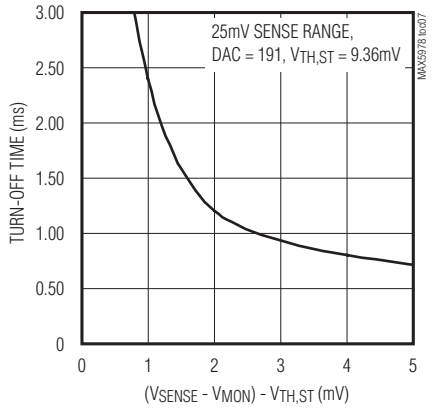
GATE-DRIVE CURRENT vs. (V_{GATE} - V_{MON})



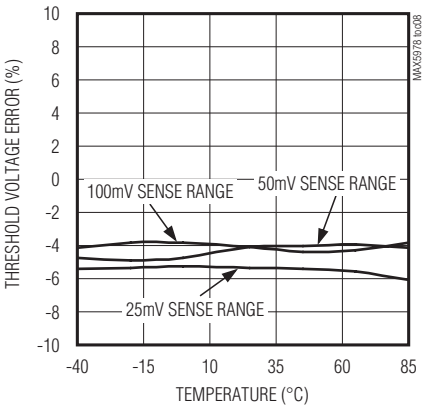
GATE-DRIVE DISCHARGE CURRENT vs. (V_{GATE} - V_{MON})



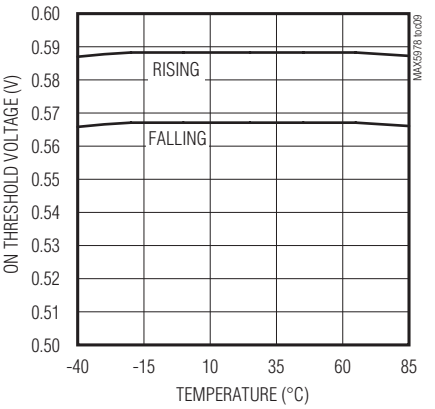
SLOW-COMPARATOR TURN-OFF TIME vs. VOLTAGE OVERDRIVE



SLOW-COMPARATOR THRESHOLD VOLTAGE ERROR vs. TEMPERATURE



ON THRESHOLD VOLTAGE vs. TEMPERATURE

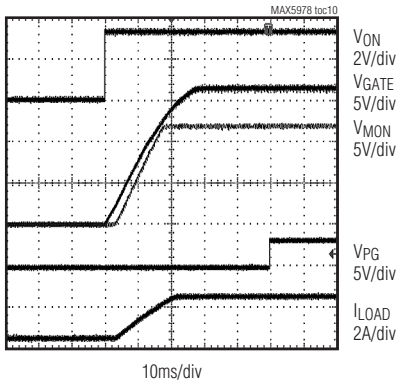


0 to 16V, Hot-Swap Controller with 10-Bit Current, Voltage Monitor, and 4 LED Drivers

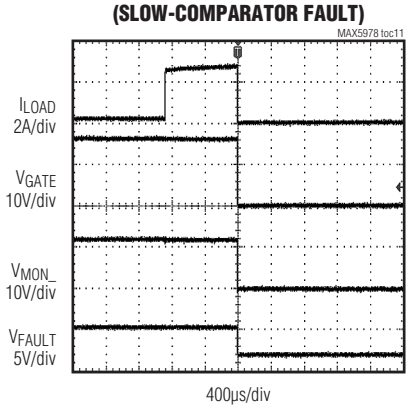
Typical Operating Characteristics (continued)

(V_{IN} = 3.3V, T_A = +25°C, unless otherwise noted.)

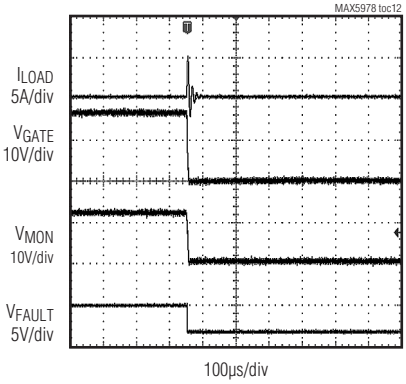
STARTUP WAVEFORM



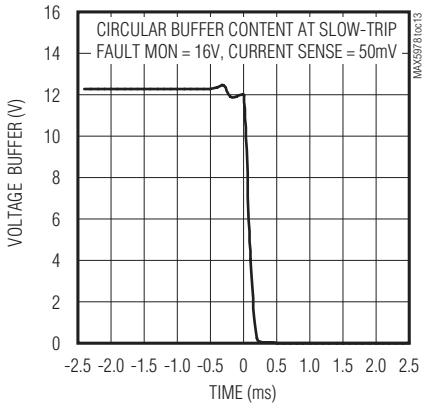
TURN-OFF WAVEFORM (SLOW-COMPARATOR FAULT)



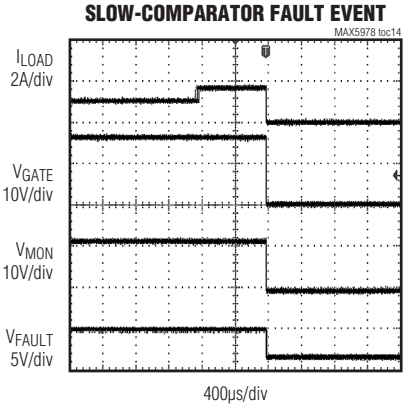
TURN-OFF WAVEFORM (FAST-COMPARATOR FAULT/SHORT-CIRCUIT RESPONSE)



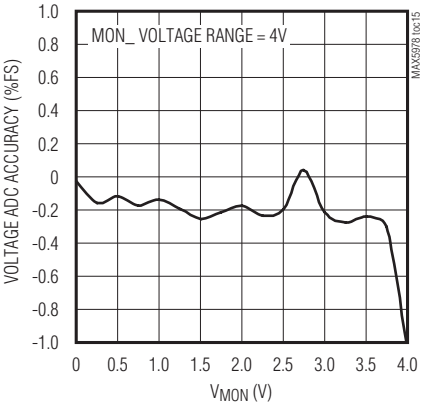
VOLTAGE BUFFER vs. TIME



SLOW-COMPARATOR FAULT EVENT



VOLTAGE ADC ACCURACY vs. MON VOLTAGE

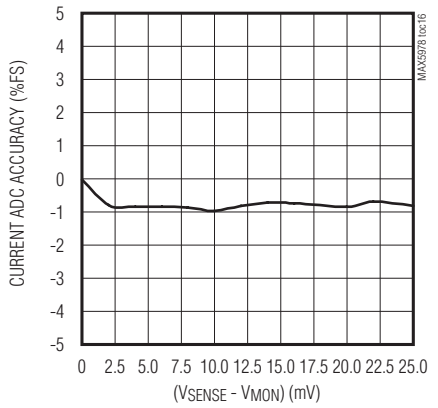


0 to 16V, Hot-Swap Controller with 10-Bit Current, Voltage Monitor, and 4 LED Drivers

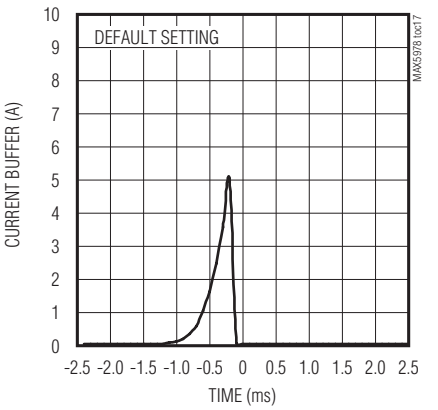
Typical Operating Characteristics (continued)

(V_{IN} = 3.3V, T_A = +25°C, unless otherwise noted.)

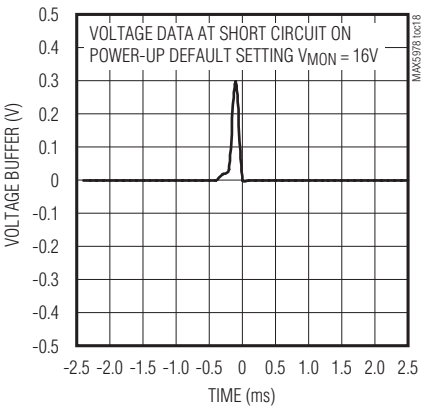
CURRENT ADC ACCURACY vs. (V_{SENSE} - V_{MON})



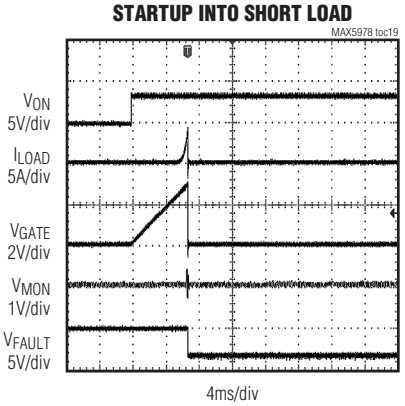
CURRENT BUFFER vs. TIME



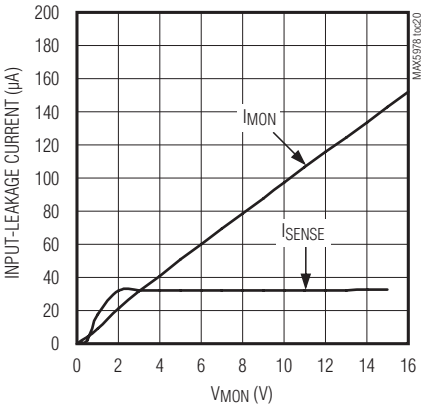
VOLTAGE BUFFER vs. TIME



STARTUP INTO SHORT LOAD

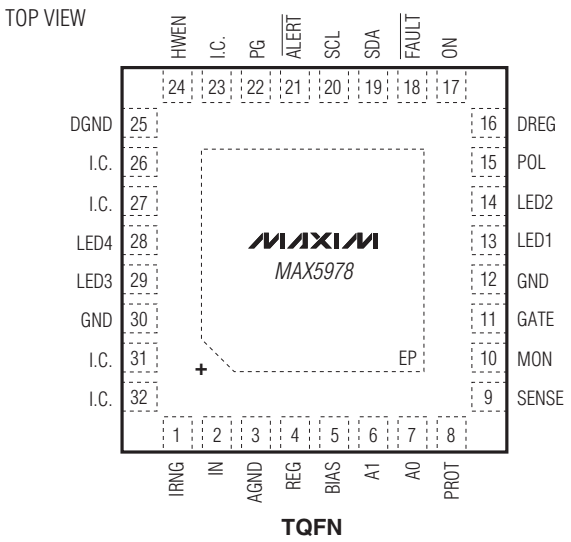


INPUT LEAKAGE CURRENT vs. MON VOLTAGE



0 to 16V, Hot-Swap Controller with 10-Bit Current, Voltage Monitor, and 4 LED Drivers

Pin Configuration



Pin Description

PIN	NAME	FUNCTION
1	IRNG	Three-State Current-Sense Range Selection Input. Set the circuit-breaker threshold range by connecting to DGND, DREG, or leave unconnected.
2	IN	Power-Supply Input. Connect to a voltage from 2.7V to 16V. Bypass IN to AGND with a 1µF ceramic capacitor.
3	AGND	Analog Ground. Connect all GND and DGND to AGND externally using a star connection.
4	REG	Internal Regulator Output. Bypass REG to ground with a 1µF ceramic capacitor. Connect only to DREG and logic-input pullup resistors. Do not use to power external circuitry.
5	BIAS	BIAS Input. Connect BIAS to REG.
6	A1	Three-State I^2C Address Input 1
7	A0	Three-State I^2C Address Input 0
8	PROT	Protection Behavior Input. Three-state input sets one of three different response options for undervoltage and overvoltage events.
9	SENSE	Current-Sense Input. Connect SENSE to the source of an external MOSFET and to one end of R_{SENSE}.
10	MON	Voltage-Monitoring Input
11	GATE	Gate-Drive Output. Connect to the gate of an external n-channel MOSFET.
12	GND	Gate-Discharge Current Ground Return. Connect all GND and DGND to AGND externally using a star connection.
13	LED1	LED1 Driver
14	LED2	LED2 Driver

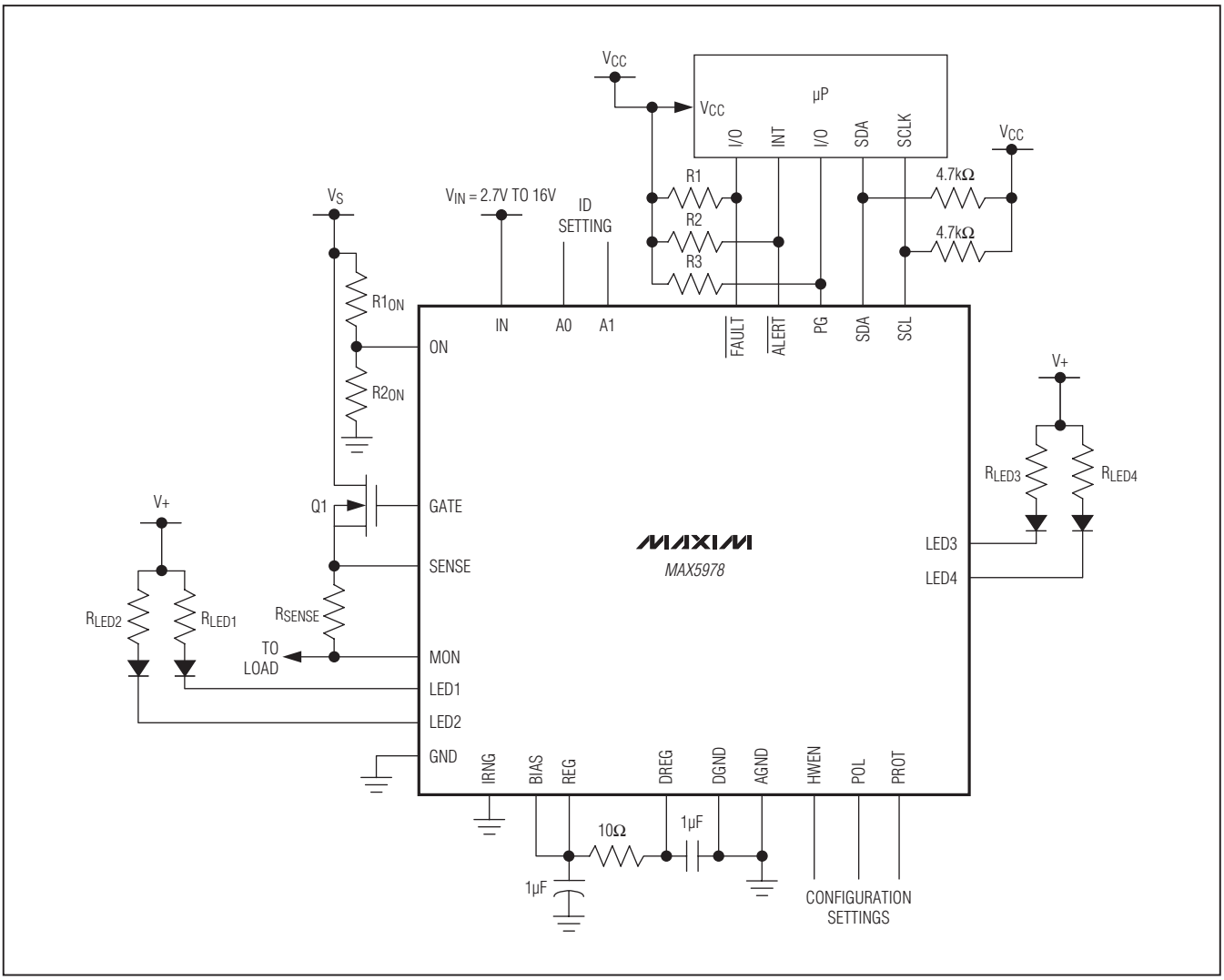
0 to 16V, Hot-Swap Controller with 10-Bit Current, Voltage Monitor, and 4 LED Drivers

Pin Description (continued)

PIN	NAME	FUNCTION
15	POL	Polarity Select Input. Connect POL to DREG for an active-high power-good (PG) output, or connect POL to GND for active-low PG output.
16	DREG	Logic Power-Supply Input. Connect to REG externally through a 10Ω resistor and bypass to DGND with a 1µF ceramic capacitor.
17	ON	Precision Turn-On Input
18	$\overline{FAULT}$	Active-Low Open-Drain Fault Output. $\overline{FAULT}$ asserts low if an overcurrent event occurs.
19	SDA	I^2C Serial Data Input/Output
20	SCL	I^2C Serial Clock Input
21	$\overline{ALERT}$	Open-Drain Alert Output. $\overline{ALERT}$ goes low during a fault to notify the system of an impending failure.
22	PG	Open-Drain Power-Good Output
23, 26, 27, 31, 32	I.C.	Internally Connected. Connect to ground.
24	HWEN	Hardware Enable Input. Connect to REG or DGND. State is read upon power-up as V_{IN} crosses the UVLO threshold and sets enable register bits with this value. After UVLO, this input becomes inactive until power is cycled.
25	DGND	Digital Ground. Connect all GND and DGND to AGND externally using a star connection.
28	LED4	LED Driver 4
29	LED3	LED Driver 3
30	GND	Ground
—	EP	Exposed Pad. EP is internally grounded. Connect EP to the ground plane using a star connection.

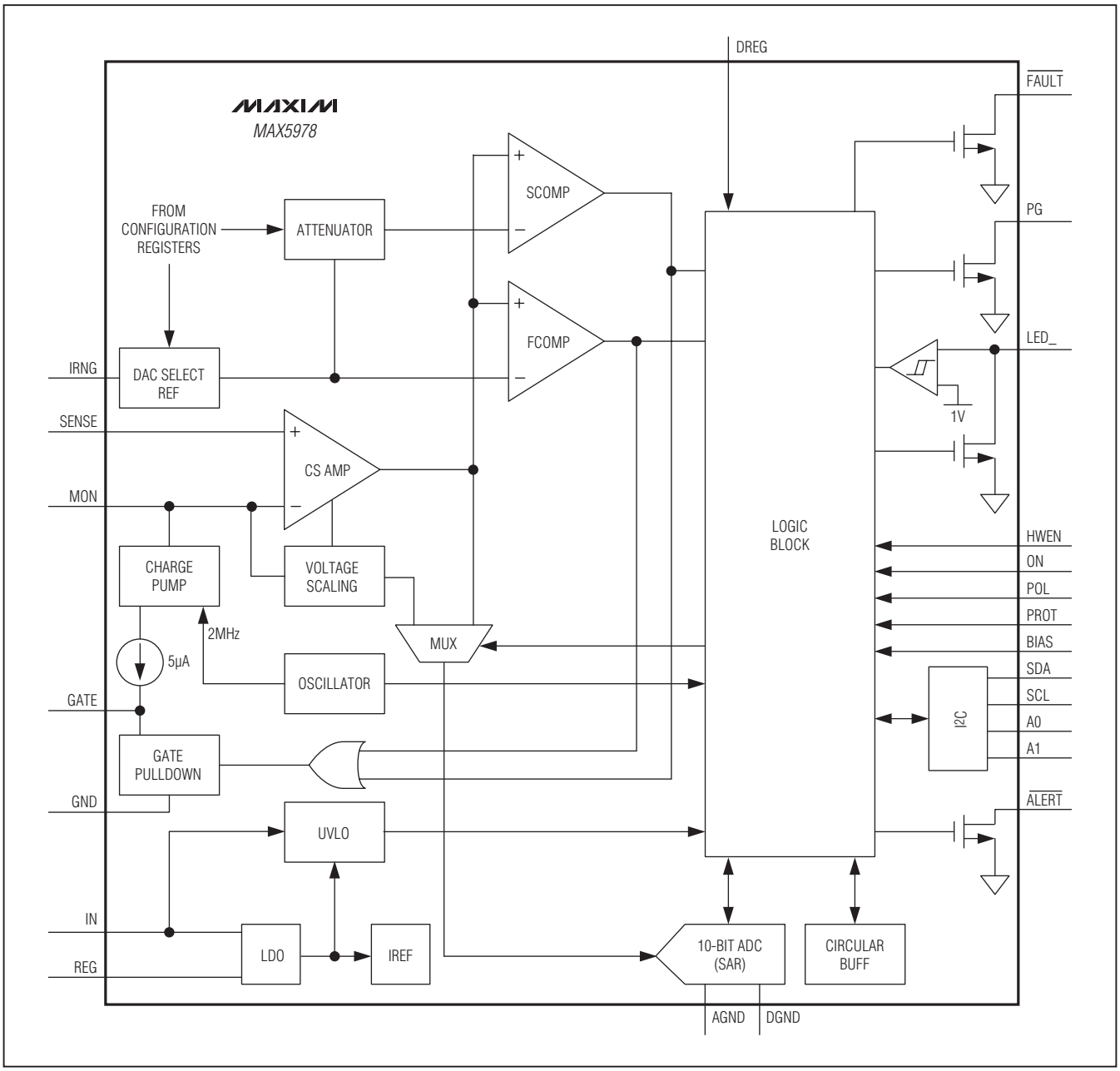
0 to 16V, Hot-Swap Controller with 10-Bit Current, Voltage Monitor, and 4 LED Drivers

Typical Operating Circuit



0 to 16V, Hot-Swap Controller with 10-Bit Current, Voltage Monitor, and 4 LED Drivers

Functional Diagram



Detailed Description

The MAX5978 includes a set of registers that are accessed through the I²C interface. Some of the registers are read only and some of the registers are read and write registers that can be updated to configure the device for a specific operation. See Tables 1a and 1b for the register maps.

Hot-Swap Channel On-Off Control

Depending on the configuration of the EN1 and EN2 bits, when V_{IN} is above the V_{UVLO} threshold and the ON input reaches its internal threshold, the device turns on the external n-channel MOSFET for the hot-swap channel, allowing power to flow to the load. The channel is enabled depending on the output of a majority function. EN1, EN2, and ON are the inputs to the majority function and the channel is enabled when two or more of these inputs are 1:

(Channel enabled) = (EN1 x EN2) + (EN1 x ON) + (EN2 x ON)

Inputs ON and EN2 can be set externally; the initial state of the EN2 bit in register chxen is set by the state of the HWEN input when V_{IN} rises above V_{UVLO}. The ON input connects to an internal precision analog comparators with a 0.6V threshold. Whenever V_{ON} is above 0.6V, the ON bit in register status1[0] is set to 1. Inputs EN1 and EN2 can be set using the I²C interface; the EN1 bit has a default value of 0. This makes it possible to enable or disable the hot-swap channel with or without using the I²C interface (see Tables 2, 3a, and 3b).

Table 1a. Register Address Map (Channel Specific)

REGISTER NAME	DESCRIPTION	REGISTER NUMBER	RESET VALUE	READ/ WRITE
adc_cs_msb	High 8 bits ([9:2]) of latest current-signal ADC result	0x00	0x00	R
adc_cs_lsb	Low 2 bits ([1:0]) of latest current-signal ADC result	0x01	0x00	R
adc_mon_msb	High 8 bits ([9:2]) of latest voltage-signal ADC result	0x02	0x00	R
adc_mon_lsb	Low 2 bits ([1:0]) of latest voltage-signal ADC result	0x03	0x00	R
min_cs_msb	High 8 bits ([9:2]) of current-signal minimum value	0x08	0xFF	R
min_cs_lsb	Low 2 bits ([1:0]) of current-signal minimum value	0x09	0x03	R
max_cs_msb	High 8 bits ([9:2]) of current-signal maximum value	0x0A	0x00	R
max_cs_lsb	Low 2 bits ([1:0]) of current-signal maximum value	0x0B	0x00	R
min_mon_msb	High 8 bits ([9:2]) of voltage-signal minimum value	0x0C	0xFF	R
min_mon_lsb	Low 2 bits ([1:0]) of voltage-signal minimum value	0x0D	0x03	R
max_mon_msb	High 8 bits ([9:2]) of voltage-signal maximum value	0x0E	0x00	R
max_mon_lsb	Low 2 bits ([1:0]) of voltage-signal maximum value	0x0F	0x00	R
uv1th_msb	High 8 bits ([9:2]) of undervoltage warning (UV1) threshold	0x1A	0x00	R/W
uv1th_lsb	Low 2 bits ([1:0]) of undervoltage warning (UV1) threshold	0x1B	0x00	R/W
uv2th_msb	High 8 bits ([9:2]) of undervoltage critical (UV2) threshold	0x1C	0x00	R/W
uv2th_lsb	Low 2 bits ([1:0]) of undervoltage critical (UV2) threshold	0x1D	0x00	R/W
ov1thr_msb	High 8 bits ([9:2]) of overvoltage warning (OV1) threshold	0x1E	0xFF	R/W
ov1thr_lsb	Low 2 bits ([1:0]) of overvoltage warning (OV1) threshold	0x1F	0x03	R/W
ov2thr_msb	High 8 bits ([9:2]) of overvoltage critical (OV2) threshold	0x20	0xFF	R/W
ov2thr_lsb	Low 2 bits ([1:0]) of overvoltage critical (OV2) threshold	0x21	0x03	R/W
oithr_msb	High 8 bits ([9:2]) of overcurrent warning threshold	0x22	0xFF	R/W
oithr_lsb	Low 2 bits ([1:0]) of overcurrent warning threshold	0x23	0x03	R/W
dac_fast	Fast-comparator threshold DAC setting	0x2E	0xBF	R/W
cbuf_ba_v	Base address for block read of 50-sample voltage-signal data buffer	0x46	—	R
cbuf_ba_i	Base address for block read of 50-sample current-signal data buffer	0x47	—	R

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Table 1b. Register Address Map (General)

REGISTER NAME	DESCRIPTION	ADDRESS (HEX CODE)	RESET VALUE	READ/ WRITE
mon_range	MON input range setting	0x18	0x00	R/W
cbuf_chx_store	Selective enabling of circular buffer	0x19	0x0F	R/W
ifast2slow	Current threshold fast-to-slow ratio setting	0x30	0x0F	R/W
status0	Slow-trip and fast-trip comparators status register	0x31	0x00	R
status1	PROT, MODE, and ON inputs status register	0x32	—	R
status2	Fast-trip threshold maximum range setting bits, from IRNG three-state input	0x33	—	R/W
status3	LATCH, POL, $\overline{\text{ALERT}}$, and PG status register	0x34	—	R
fault0	Status register for undervoltage detection (warning or critical)	0x35	0x00	R/C
fault1	Status register for overvoltage detection (warning or critical)	0x36	0x00	R/C
fault2	Status register for overcurrent detection (warning)	0x37	0x00	R/C
pgdly	Delay setting between MON measurement and PG assertion	0x38	0x00	R/W
fokey	Load register with 0xA5 to enable force-on function	0x39	0x00	R/W
foset	Register that enables force-on function	0x3A	0x00	R/W
chxen	Channel enable bits	0x3B	—	R/W
dgl_i	OC deglitch enable bits	0x3C	0x00	R/W
dgl_uv	UV deglitch enable bits	0x3D	0x00	R/W
dgl_ov	OV deglitch enable bits	0x3E	0x00	R/W
cbufrd_hibyonly	Circular buffers readout mode: 8 bit or 10 bit	0x3F	0x0F	R/W
cbuf_dly_stop	Circular buffer stop delay; number of samples recorded to the circular buffer after channel shutdown	0x40	0x19	R/W
peak_log_rst	Reset control bits for peak-detection registers	0x41	0x00	R/W
peak_log_hold	Hold control bits for peak-detection registers	0x42	0x00	R/W
LED_flash	LED flash/GPIO enable register	0x43	0x0F	R/W
LED_ph_pu	LED phase/weak pullup enable register	0x44	0x00	R/W
LED_state	LED pins voltage state register (LED pins set open)	0x45	—	R

Table 2. chxen Register Format

Description:	Channel enable bits
Resister Title:	chxen
Register Address:	0x3B

R	R	R	R	R/W	R/W	R/W	R/W	RESET VALUE
—	—	—	—	Unused	Unused	EN2	EN1	—
Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	—

Table 3a. Register Function

REGISTER ADDRESS	BIT RANGE	DESCRIPTION
0x32	[1:0]	**ON input state**
		1 = ON above 600mV channel enable threshold
		0 = ON below 600mV channel enable threshold
		Bit 0: ON input state
		Bit 1: unused
	[4]	**Unused**
	[7:6]	**Voltage critical behavior (PROT input)**
		00 = Assert $\overline{ALERT}$ upon UV/OV critical (same as UV/OV warning behavior)
		01 = Assert $\overline{ALERT}$ and deassert PG upon UV/OV critical
		10 = Assert $\overline{ALERT}$, deassert PG, and shut down channel upon UV/OV critical
		11 = (Not possible)

Table 3b. status1 Register Format

Description:	Fault-detection behavior (three-state PROT input) and ON input status register
Resister Title:	status1
Register Address:	0x32

R	R	R	R	R	R	R	R	RESET VALUE
prot[1]	prot[0]	—	Unused	—	—	Unused	ON	—
Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	—

Figure 1 shows the detailed logic operation of the hot-swap enable signals EN1, EN2, and ON, as well as the effect of various fault conditions.

An input undervoltage threshold control for enabling the hot-swap channel can be implemented by placing a resistive divider between the drain of the hot-swap MOSFET and ground, with the midpoint connected to ON. The turn-on threshold voltage for the channel is then:

$$V_{EN} = 0.6V \times (R1 + R2)/R2$$

The maximum rating for the ON input is 6V; do not exceed this value.

Startup

When all conditions for channel turn-on are met, the external n-channel MOSFET switch is fully enhanced with a typical gate-to-source voltage of 5V to ensure a low drain-to-source resistance. The charge pump at the GATE driver sources 5µA to control the output voltage turn-on voltage slew rate. An external capacitor can be added from GATE to GND to further reduce the voltage slew rate. Placing a 1kΩ resistor in series with this capacitance prevents the added capacitance from increasing the gate turn-off time. Total inrush current is the load current summed with the product of the gate-voltage slew rate dV/dt and the load capacitance.

To determine the output dV/dt during startup, divide the GATE pullup current $I_{G(UP)}$ by the gate-to-ground capacitance. The voltage at the source of the external MOSFET follows the gate voltage, so the load dV/dt is the same as the gate dV/dt. Inrush current is the product of the dV/dt and the load capacitance. The time to start up t_{SU} is the hot-swap voltage V_S divided by the output dV/dt.

Be sure to choose an external MOSFET that can handle the power dissipated during startup. The inrush current is roughly constant during startup and the voltage drop across the MOSFET (drain to source) decreases linearly as the load capacitance charges. The resulting power dissipation is, therefore, roughly equivalent to a single pulse of magnitude (V_S x inrush current)/2 and

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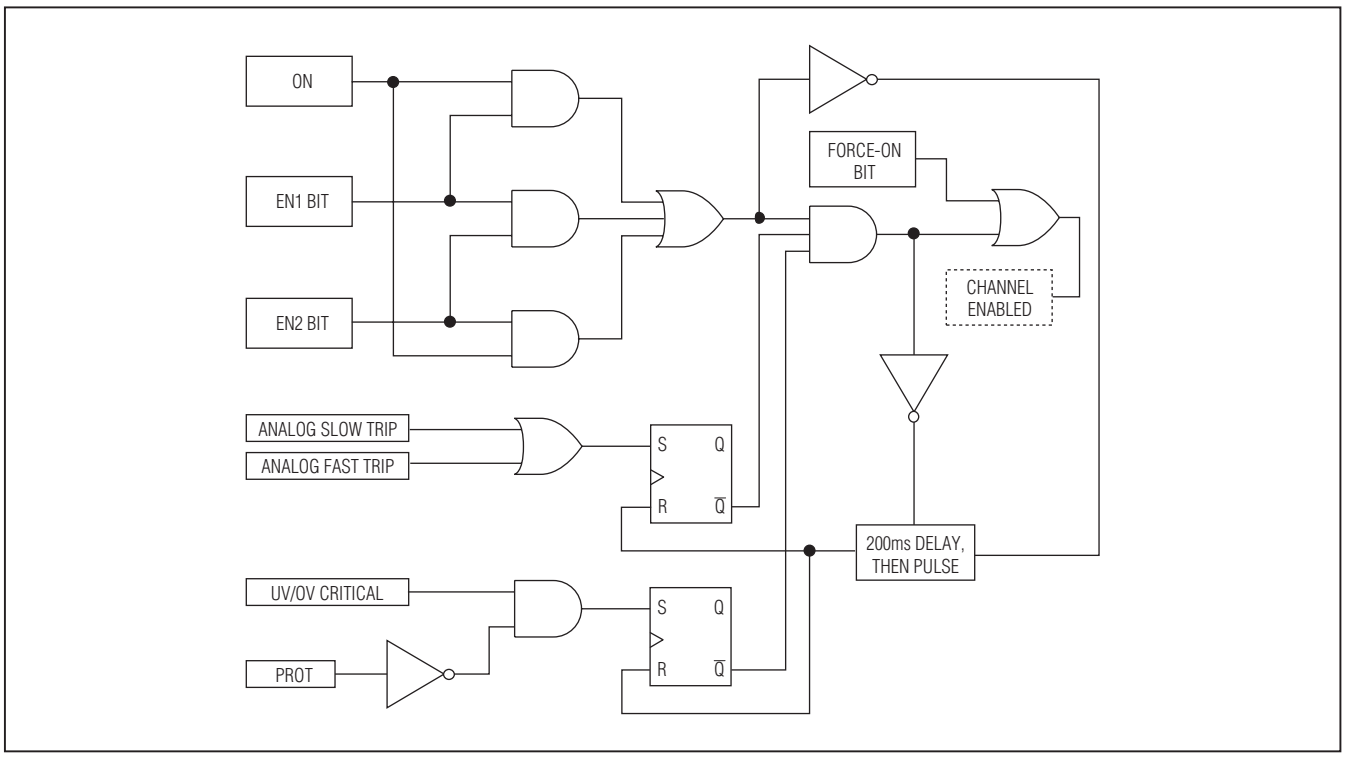

Figure 1. Channel On-Off Control Logic Functional Schematic

duration t_{SU}. Refer to the thermal resistance charts in the MOSFET data sheet to determine the junction temperature rise during startup, and ensure that this does not exceed the maximum junction temperature for worst-case ambient conditions.

Circuit-Breaker Protection

As the channel is turned on and during normal operation, two analog comparators are used to detect an overcurrent condition by sensing the voltage across an external resistor connected between SENSE and MON. If the voltage across the sense resistor is less than the slow-trip and fast-trip circuit-breaker thresholds, the GATE output remains high. If either of the thresholds is exceeded due to an overcurrent condition, the gate of the MOSFET is pulled down to MON by an internal 500mA current source.

The higher of the two comparator thresholds, the fast trip, is set by an internal 8-bit DAC (see Table 7), within one of three configurable full-scale current-sense ranges: 25mV, 50mV, or 100mV (see Tables 6a and 6b). The 8-bit fast-trip threshold DAC can be programmed from 40% to 100% of the selected full-scale current-sense range. The slow-trip threshold follows the fast-trip threshold as one of four programmable ratios, set by the ifast2slow register (see Tables 4a and 4b).

The fast-trip threshold is always higher than the slow-trip threshold, and the fast-trip comparator responds very quickly to protect the system against sudden, severe overcurrent events. The slower response of the slow-trip comparator varies depending upon the amount of overdrive beyond the slow-trip threshold. If the overdrive is small and short lived, the comparator will not shut down the affected channel. As the overcurrent event increases in magnitude, the response time of the slow-trip comparator decreases. This scheme provides good noise rejection and spurious overcurrent transients near the slow-trip threshold, while aggressively protecting the system against larger overcurrent events that occur as a result of a load fault.

Table 4a. ifast2slow Register Format

Description:	Current threshold fast-to-slow setting bits							
Resister Title:	ifast2slow							
Register Address:	0x30							
R	**R**	**R**	**R**	**R/W**	**R/W**	**R/W**	**R/W**	**RESET VALUE**
—	—	—	—	Unused	Unused	FS1	FS0	0x0F
Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	—

Table 4b. Setting Fast-Trip to Slow-Trip Threshold Ratio

FS1	FS0	FAST-TRIP TO SLOW-TRIP RATIO (%)
0	0	125
0	1	150
1	0	175
1	1	200

Setting Circuit-Breaker Thresholds

To select and set the device slow-trip and fast-trip comparator thresholds, use the following procedure:

1) Select one of four ratios between the fast-trip threshold and the slow-trip threshold: 200%, 175%, 150%, or 125%. A system that experiences brief but large transient load currents should use a higher ratio, whereas a system that operates continuously at higher average load currents might benefit from a smaller ratio to ensure adequate protection. The ratio is set by writing to the ifast2slow register. (The default setting on power-up is 200%.)

2) Determine the slow-trip threshold $V_{TH,ST}$ based on the anticipated maximum continuous load current during normal operation, and the value of the current-sense resistor. The slow-trip threshold should include some margin (possibly 20%) above the maximum load current to prevent spurious circuit-breaker shutdown and to accommodate passive component tolerances:

$$V_{TH,ST} = R_{SENSE} \times I_{LOAD,MAX} \times 120\%$$

3) Calculate the necessary fast-trip threshold $V_{TH,FT}$ based on the ratio set in step 1:

$$V_{TH,FT} = V_{TH,ST} \times (\text{ifast2slow ratio})$$

4) Select one of the three maximum current-sense ranges: 25mV, 50mV, or 100mV. The current-sense range is initially set upon power-up by the state of the IRNG input, but can be altered at any time by writing to the status2 register. For maximum accuracy and best measurement resolution, select the lowest current-sense range that is larger than the $V_{TH,FT}$ value calculated in step 3.

5) Program the fast-trip and slow-trip thresholds by writing an 8-bit value to the dac_fast register. This 8-bit value is determined from the desired $V_{TH,ST}$ value that was calculated in step 2, the threshold ratio from step 1, and the current-sense range from step 4:

$$DAC = V_{TH,ST} \times 255 \times (\text{ifast2slow ratio}) / (\text{IRNG current-sense range})$$

The device provides a great deal of system flexibility because the current-sense range, DAC setting, and threshold ratio can be changed “on the fly” for systems that must protect a wide range of interchangeable load devices, or for systems that control the allocation of power to smart loads. Table 5 shows the specified ranges for the fast-trip and slow-trip thresholds for all combinations of current-sense range and threshold ratio.

When an overcurrent event causes the device to shut down the power channel, the open-drain $\overline{FAULT}$ output alerts the system. Figure 2 shows the operation and fault-management flowchart.

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Table 5. Specified Current-Sense and Circuit-Breaker Threshold Ranges

IRNG INPUT	DAC OUTPUT RANGE (DEFAULT = FULL SCALE) (mV)	FAST-TRIP THRESHOLD RANGE (mV)	GAIN (2 BIT) (V_{FAST}/V_{SLOW}) ifast2slow (DEFAULT = 11)	SLOW-TRIP THRESHOLD RANGE (mV)
Low	10 to 25	10 to 25	00 (125%)	8.00 to 20.00
			01 (150%)	6.67 to 16.67
			10 (175%)	5.71 to 14.29
			11 (200%)	5.00 to 12.50
High	20 to 50	20 to 50	00 (125%)	16.00 to 40.00
			01 (150%)	13.33 to 33.33
			10 (175%)	11.48 to 28.57
			11 (200%)	10.00 to 25.00
Unconnected	40 to 100	40 to 100	00 (125%)	32.00 to 80.00
			01 (150%)	26.67 to 66.67
			10 (175%)	22.86 to 57.14
			11 (200%)	20.00 to 50.00

Table 6a. IRNG Input Status Register Format

Description:	Fast-trip threshold maximum range-setting bits, from IRNG three-state input
Resister Title:	status2
Register Address:	0x33

R	R	R	R	R/W	R/W	R/W	R/W	RESET VALUE
—	—	—	—	Unused	Unused	IRNG1	IRNG0	—
Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	—

Table 6b. Setting Current-Sense Range

IRNG PIN STATE	IRNG1	IRNG0	MAXIMUM CURRENT-SENSE SIGNAL (mV)
Low	1	0	25
High	0	1	50
Open	0	0	100

Table 7. dac_ch_ Register Format

Description:	Fast-comparator threshold DAC setting
Register Title:	dac_fast
Register Addresses:	0x2E

R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	RESET VALUE
DAC[7]	DAC[6]	DAC[5]	DAC[4]	DAC[3]	DAC[2]	DAC[1]	DAC[0]	0xBF
Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	—

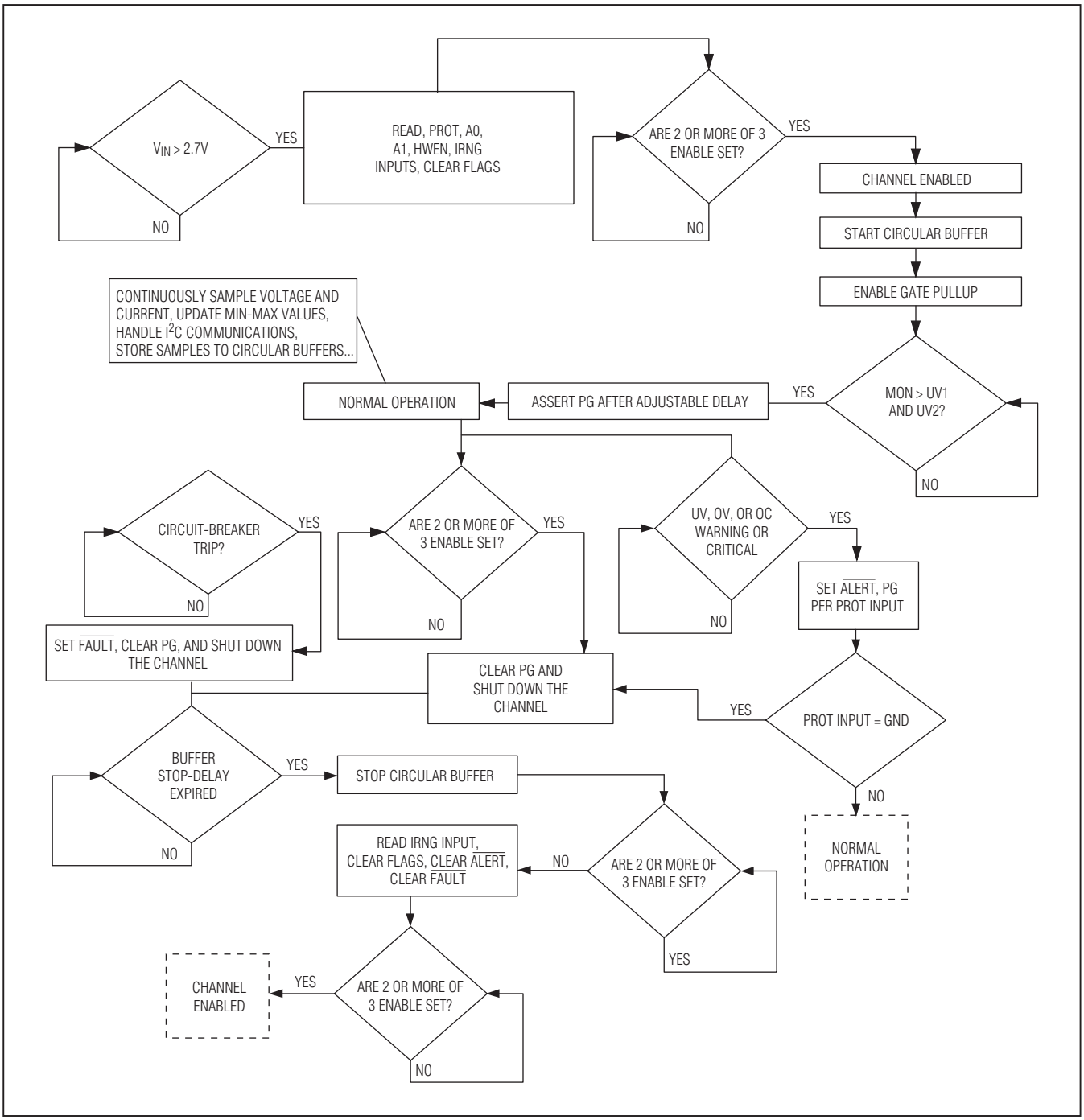

Figure 2. Operation and Fault-Management Flowchart for Hot-Swap Channel

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Digital Current Monitoring

The current-sense signal is sampled by the internal 10-bit, 10ksps ADC, and the most recent results are stored in registers for retrieval through the I²C interface. The current conversion values are 10 bits wide, with the 8 high-order bits written to one 8-bit register and the 2 low-order bits written to the next-higher 8-bit register address (Tables 8 and 9). This allows use of just the high-order byte in applications where 10-bit precision is not required. This split 8-bit/2-bit storage scheme is used throughout the device for ADC conversion results and digital comparator thresholds.

Once the PG output is asserted, the current-sense samples are continuously compared to the programmable overcurrent warning register value. If the measured current value exceeds the warning level, the $\overline{ALERT}$ output is asserted. The device response to this digital comparator is not altered by the setting of the PROT input (Tables 10 and 11).

Table 8. ADC Current-Conversion Results Register Format (High-Order Bits)

Description:	Most recent current-conversion result, high-order bits [9:2]
Register Title:	adc_cs_msb
Register Addresses:	0x00

R	R	R	R	R	R	R	R	RESET VALUE
inew_9	inew_8	inew_7	inew_6	inew_5	inew_4	inew_3	inew_2	0x00
Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	—

Table 9. ADC Current-Conversion Results Register Format (Low-Order Bits)

Description:	Most recent current-conversion result, low-order bits [0:1]
Register Title:	adc_cs_ lsb
Register Addresses:	0x01

R	R	R	R	R	R	R	R	RESET VALUE
—	—	—	—	—	—	inew_1	inew_0	0x00
Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	—

Table 10. Overcurrent Warning Threshold Register Format (High-Order Bits)

Description:	Overcurrent warning threshold high-order bits [9:2]
Register Title:	oithr_msb
Register Addresses:	0x22

R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	RESET VALUE
oi_9	oi_8	oi_7	oi_6	oi_5	oi_4	oi_3	oi_2	0xFF
Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	—

Table 11. Overcurrent Warning Threshold Register Format (Low-Order Bits)

Description:	Overcurrent warning threshold low-order bits [1:0]
Register Title:	oithr_lsb
Register Addresses:	0x23

R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	RESET VALUE
—	—	—	—	—	—	oi_1	oi_0	0x03
Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	—

Minimum and Maximum Value Detection for Current-Measurement Values

Current-sense measurement values from the ADC are continuously compared with the contents of minimum- and maximum-value registers, and if the most recent measurement exceeds the stored maximum, or is less than the stored minimum, the corresponding register is updated with the new value. These "peak-detection" registers are read/write accessible through the I²C interface (Tables 12–15). The minimum-value registers are reset to 0xFF and the maximum-value registers are reset to 0x00. These reset values are loaded upon startup of the channel or at any time as commanded by register peak_log_rst (Table 35).

Table 12. ADC Minimum Current-Conversion Register Format (High-Order Bits)

Description:	Minimum current-conversion result high-order bits [9:2]
Register Title:	min_cs_msb
Register Addresses:	0x08

R	R	R	R	R	R	R	R	RESET VALUE
imin_9	imin_8	imin_7	imin_6	imin_5	imin_4	imin_3	imin_2	0xFF
Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	—

Table 13. ADC Minimum Current-Conversion Register Format (Low-Order Bits)

Description:	Minimum current-conversion result low-order bits [1:0]
Register Title:	min_cs_ lsb
Register Addresses:	0x09

R	R	R	R	R	R	R	R	RESET VALUE
—	—	—	—	—	—	imin_1	imin_0	0x03
Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	—

Table 14. ADC Maximum Current-Conversion Register Format (High-Order Bits)

Description:	Maximum current-conversion result high-order bits [9:2]
Register Title:	max_cs_msb
Register Addresses:	0x0A

R	R	R	R	R	R	R	R	RESET VALUE
imax_9	imax_8	imax_7	imax_6	imax_5	imax_4	imax_3	imax_2	0x00
Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	—

Table 15. ADC Maximum Current-Conversion Register Format (Low-Order Bits)

Description:	Maximum current-conversion result low-order bits [1:0]
Register Title:	max_cs_lsb
Register Addresses:	0x0B

R	R	R	R	R	R	R	R	RESET VALUE
—	—	—	—	—	—	imax_1	imax_0	0x00
Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	—

0 to 16V, Hot-Swap Controller with 10-Bit Current, Voltage Monitor, and 4 LED Drivers

Digital Voltage Monitoring and Power-Good Output

The voltage at the load (MON input) is sampled by the internal ADC. The MON full-scale voltage can be set to 16V, 8V, 4V, or 2V by writing to register mon_range. The default range is 16V (Tables 16 and 17).

The most recent voltage-conversion results can be read from the adc_mon_msb and adc_mon_lsb registers (see Tables 18 and 19).

Digital Undervoltage- and Overvoltage-Detection Thresholds

The most recent voltage values are continuously compared to four programmable limits, comprising two undervoltage (UV) levels (see Tables 20 to 23) and two overvoltage (OV) levels (see Tables 24 to 27).

If PG is asserted and the voltage is outside the warning limits, the $\overline{ALERT}$ output is asserted low. Depending on the status of the prot[] bits in register status1[7:6], the

Table 16. ADC Voltage Monitor Settings Register Format

Description:	ADC voltage monitor full-scale range settings (for MON input)
Register Title:	mon_range
Register Addresses:	0x18

R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	RESET VALUE
—	—	—	—	Unused	Unused	MON_rng1	MON_rng0	0x00
Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	—

Table 17. ADC Full-Scale Voltage Setting

MON_rng1	MON_rng0	ADC FULL-SCALE VOLTAGE (V)
0	0	16
0	1	8
1	0	4
1	1	2

Table 18. ADC Voltage-Conversion Result Register Format (High-Order Bits)

Description:	Most recent voltage-conversion result, high-order bits [9:2]
Register Title:	adc_mon_msb
Register Addresses:	0x02

R	R	R	R	R	R	R	R	RESET VALUE
vnew_9	vnew_8	vnew_7	vnew_6	vnew_5	vnew_4	vnew_3	vnew_2	0x00
Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	—

Table 19. ADC Voltage-Conversion Result Register Format (Low-Order Bits)

Description:	Most recent voltage-conversion result, low-order bits [1:0]
Register Title:	adc_mon_lsb
Register Addresses:	0x03

R	R	R	R	R	R	R	R	RESET VALUE
—	—	—	—	—	—	vnew_1	vnew_0	0x00
Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	—

device can also deassert the PG output or turn off the external MOSFET when the voltage is outside the critical limits (see Figure 3). Table 28 shows the behavior for the three possible states of the PROT input. Note that the PROT input does not affect the device response to the UV or OV warning digital comparators; it only determines the system response to the critical digital comparators (see Tables 3a, 3b, and 28).

In a typical application, the UV1 and OV1 thresholds would be set closer to the nominal output voltage, and the UV2 and OV2 thresholds would be set further from nominal. This provides a "progressive" response to a voltage excursion. However, the thresholds can be configured in any arrangement or combination as desired to suit a given application.

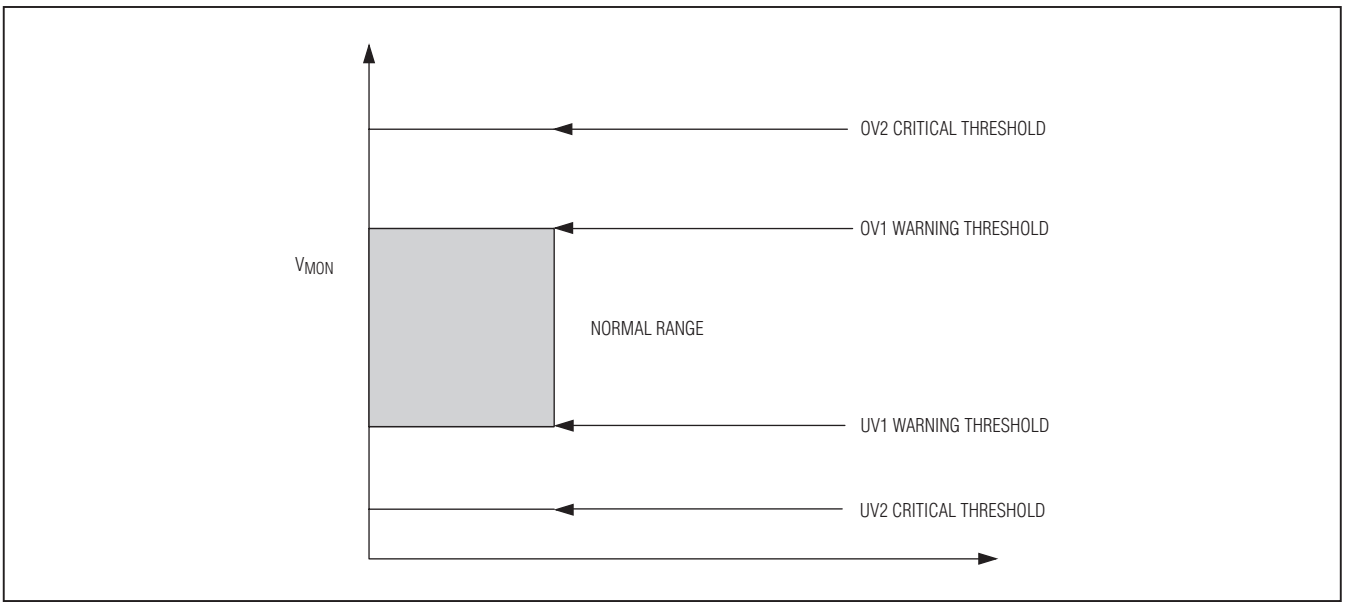

Figure 3. Graphical Representation of Typical UV and OV Thresholds Configuration

Table 20. Undervoltage Warning Threshold Register Format (High-Order Bits)

Description:	Undervoltage warning threshold high-order bits [9:2]
Register Title:	uv1th_msb
Register Addresses:	0x1A

R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	RESET VALUE
uv1_9	uv1_8	uv1_7	uv1_6	uv1_5	uv1_4	uv1_3	uv1_2	0x00
Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	—

Table 21. Undervoltage Warning Threshold Register Format (Low-Order Bits)

Description:	Undervoltage warning threshold low-order bits [1:0]
Register Titles:	uv1th_lsb
Register Addresses:	0x1B

R	R	R	R	R	R	R/W	R/W	RESET VALUE
—	—	—	—	—	—	uv1_1	uv1_0	0x00
Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	—

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Table 22. Undervoltage Critical Threshold Register Format (High-Order Bits)

Description:	Undervoltage critical threshold high-order bits [9:2]
Register Title:	uv2th_msb
Register Addresses:	0x1C

R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	RESET VALUE
uv2_9	uv2_8	uv2_7	uv2_6	uv2_5	uv2_4	uv2_3	uv2_2	0x00
Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	—

Table 23. Undervoltage Critical Threshold Register Format (Low-Order Bits)

Description:	Undervoltage critical threshold low-order bits [1:0]
Register Title:	uv2th_lsb
Register Addresses:	0x1D

R	R	R	R	R	R	R/W	R/W	RESET VALUE
—	—	—	—	—	—	uv2_1	uv2_0	0x00
Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	—

Table 24. Overvoltage Warning Threshold Register Format (High-Order Bits)

Description:	Overvoltage warning threshold high-order bits [9:2]
Register Title:	ov1thr_msb
Register Addresses:	0x1E

R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	RESET VALUE
ov1_9	ov1_8	ov1_7	ov1_6	ov1_5	ov1_4	ov1_3	ov1_2	0xFF
Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	—

Table 25. Overvoltage Warning Threshold Register Format (Low-Order Bits)

Description:	Overvoltage warning threshold low-order bits [1:0]
Register Title:	ov1thr_lsb
Register Addresses:	0x1F

R	R	R	R	R	R	R/W	R/W	RESET VALUE
—	—	—	—	—	—	ov1_1	ov1_0	0x03
Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	—

Table 26. Overvoltage Critical Threshold Register Format (High-Order Bits)

Description:	Overvoltage critical threshold high-order bits [9:2]
Register Title:	ov2thr_msb
Register Addresses:	0x20

R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	RESET VALUE
ov2_9	ov2_8	ov2_7	ov2_6	ov2_5	ov2_4	ov2_3	ov2_2	0xFF
Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	—

Table 27. Overvoltage Critical Threshold Register Format (Low-Order Bits)

Description:	Overvoltage critical threshold low-order bits [1:0]							
Register Title:	ov2thr_lsb							
Register Addresses:	0x21							
R	**R**	**R**	**R**	**R**	**R/W**	**R/W**	**R/W**	**RESET VALUE**
—	—	—	—	—	—	ov2_1	ov2_0	0x03
Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	—

Table 28. PROT Input and prot[] Bits

PROT INPUT STATE	prot[1]	prot[0]	UV/OV WARNING ACTION	UV/OV CRITICAL ACTION
Low	0	0	Assert $\overline{\text{ALERT}}$	Assert $\overline{\text{ALERT}}$, clear PG, shut down channel
High	0	1	Assert $\overline{\text{ALERT}}$	Assert $\overline{\text{ALERT}}$, clear PG
Unconnected	1	0	Assert $\overline{\text{ALERT}}$	Assert $\overline{\text{ALERT}}$

Table 29. status3 Register Format

Description:	Power-good status register: POL, ALERT, and power-good bits							
Register Title:	status3							
Register Address:	0x34							
R	**R**	**R**	**R/W**	**R**	**R**	**R**	**R**	**RESET VALUE**
—	—	POL	ALERT	—	—	Unused	pg[0]	—
Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	—

Table 30a. Power-Good Assertion Delay-Time Register Format

Description:	Power-good assertion delay-time register							
Register Title:	pgdly							
Register Address:	0x38							
R	**R**	**R**	**R**	**R/W**	**R/W**	**R/W**	**R/W**	**RESET VALUE**
—	—	—	—	Unused	Unused	pgdly1	pgdly0	0x00
Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	—

Table 30b. Power-Good Assertion Delay

pgdly1	pgdly0	PG ASSERTION DELAY (ms)
0	0	50
0	1	100
1	0	200
1	1	400

Power-Good Detection and PG Output

The PG output is asserted when the voltage at MON is between the undervoltage and overvoltage critical limits. The status of the power-good signal is maintained in register status3[0]. A value of 1 in the pg[] bit indicates a power-good condition, regardless of the POL setting, which only affects the PG output pin polarity. The open-drain PG output can be configured for active-high or active-low status indication by the state of the POL input (see Table 29).

The POL input sets the value of status3[5], which is a read-only bit; the state of the POL input can be changed at any time during operation and the polarity of the PG output changes accordingly.

The assertion of the PG output is delayed by a user-selectable time delay of 50ms, 100ms, 200ms, or 400ms (see Tables 30a and 30b).